

Dual Series Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

- Extremely Fast Switching Speed
- Low Forward Voltage — 0.35 Volts (Typ) @ $I_F = 10 \text{ mAdc}$
- We declare that the material of product compliance with RoHS requirements.

ORDERING INFORMATION

| Device | Marking | Shipping |
|-------------|---------|-----------------|
| LBAT54SLT1G | LD3 | 3000/Tape&Reel |
| LBAT54SLT3G | LD3 | 10000/Tape&Reel |

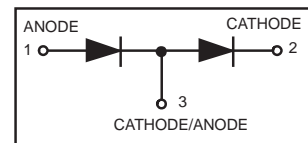
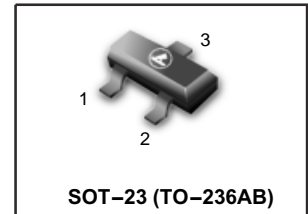
MAXIMUM RATINGS ($T_J = 125^\circ\text{C}$ unless otherwise noted)

| Rating | Symbol | Value | Unit |
|--|-----------|-------------|----------------------------|
| Reverse Voltage | V_R | 30 | Volts |
| Forward Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C | P_D | 225 1.8 | mW mW/ $^\circ\text{C}$ |
| Forward Current (DC) | I_F | 200 Max | mA |
| Junction Temperature | T_J | 125 Max | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | -55 to +150 | $^\circ\text{C}$ |

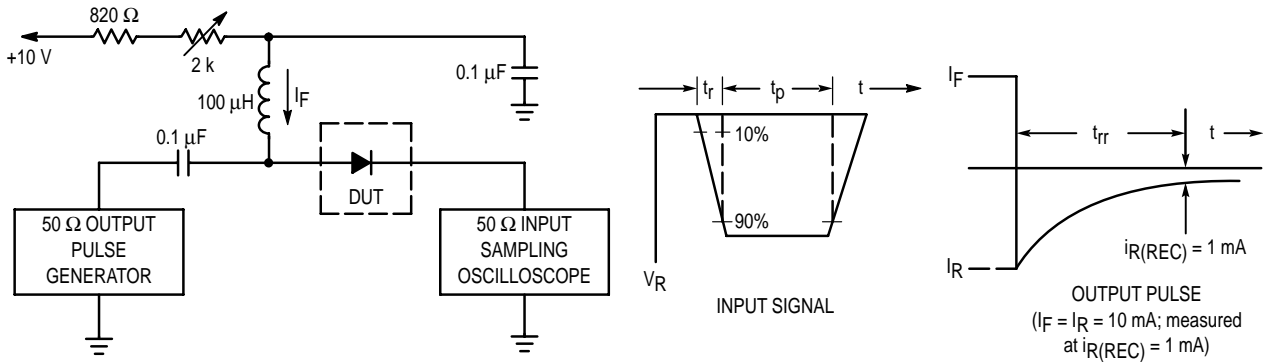
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|-------------|-----|------|------|-----------------|
| Reverse Breakdown Voltage ($I_R = 10 \mu\text{A}$) | $V_{(BR)R}$ | 30 | — | — | Volts |
| Total Capacitance ($V_R = 1.0 \text{ V}$, $f = 1.0 \text{ MHz}$) | C_T | — | — | 10 | pF |
| Reverse Leakage ($V_R = 25 \text{ V}$) | I_R | — | 0.5 | 2.0 | μAdc |
| Forward Voltage ($I_F = 0.1 \text{ mAdc}$) | V_F | — | 0.22 | 0.24 | Vdc |
| Forward Voltage ($I_F = 30 \text{ mAdc}$) | V_F | — | 0.41 | 0.5 | Vdc |
| Forward Voltage ($I_F = 100 \text{ mAdc}$) | V_F | — | 0.52 | 1.0 | Vdc |
| Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}$, $I_{R(REC)} = 1.0 \text{ mAdc}$) Figure 1 | t_{rr} | — | — | 5.0 | ns |
| Forward Voltage ($I_F = 1.0 \text{ mAdc}$) | V_F | — | 0.29 | 0.32 | Vdc |
| Forward Voltage ($I_F = 10 \text{ mAdc}$) | V_F | — | 0.35 | 0.40 | Vdc |
| Forward Current (DC) | I_F | — | — | 200 | mAdc |
| Repetitive Peak Forward Current | I_{FRM} | — | — | 300 | mAdc |
| Non-Repetitive Peak Forward Current ($t < 1.0 \text{ s}$) | I_{FSM} | — | — | 600 | mAdc |

LBAT54SLT1G



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- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10 mA.
- 2. Input pulse is adjusted so $I_R(\text{peak})$ is equal to 10 mA.
- 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

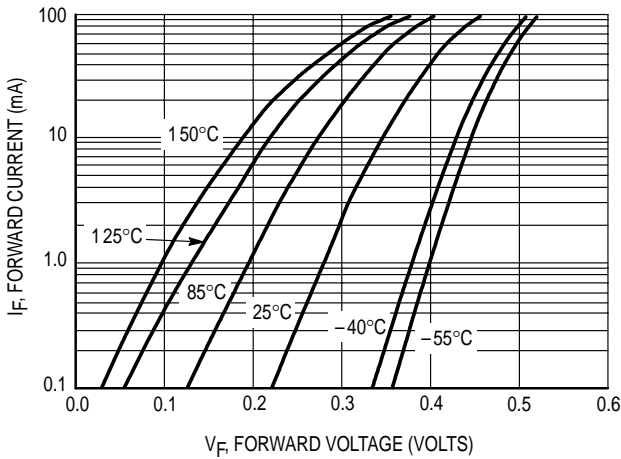


Figure 2. Forward Voltage

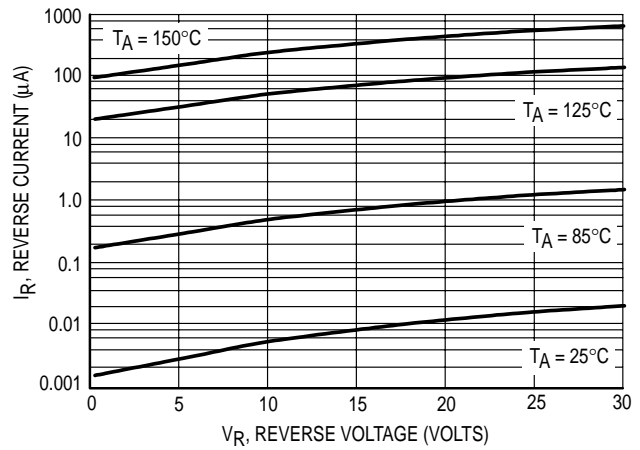


Figure 3. Leakage Current

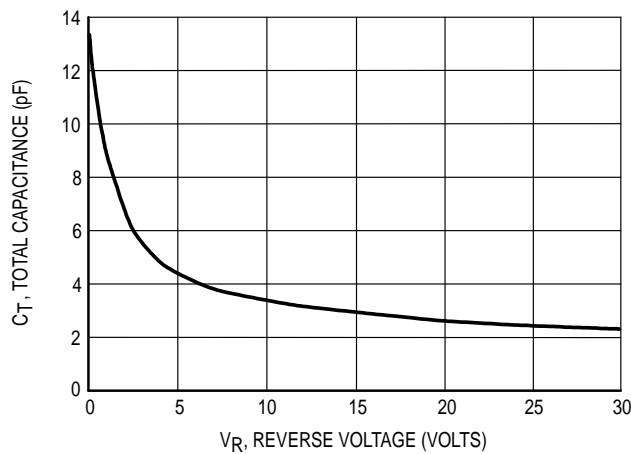
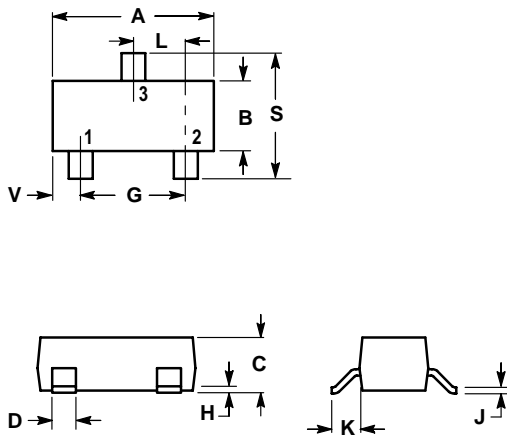


Figure 4. Total Capacitance

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SOT-23
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.



| DIM | INCHES | | MILLIMETERS | |
|-----|--------|--------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.1102 | 0.1197 | 2.80 | 3.04 |
| B | 0.0472 | 0.0551 | 1.20 | 1.40 |
| C | 0.0350 | 0.0440 | 0.89 | 1.11 |
| D | 0.0150 | 0.0200 | 0.37 | 0.50 |
| G | 0.0701 | 0.0807 | 1.78 | 2.04 |
| H | 0.0005 | 0.0040 | 0.013 | 0.100 |
| J | 0.0034 | 0.0070 | 0.085 | 0.177 |
| K | 0.0140 | 0.0285 | 0.35 | 0.69 |
| L | 0.0350 | 0.0401 | 0.89 | 1.02 |
| S | 0.0830 | 0.1039 | 2.10 | 2.64 |
| V | 0.0177 | 0.0236 | 0.45 | 0.60 |

